



IXFK30N110P Information



For Reference Only

Part Number IXFK30N110P

Manufacturer IXYS

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description MOSFET N-CH 1100V 30A TO-264

Package TO-264-3, TO-264AA

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









IXFK30N110P Specifications

Manufacturer Part Number	IXFK30N110P
Manufacturer	IXYS
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-264-3, TO-264AA
Series	HiPerFET?, PolarP2?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	1100V
Current - Continuous Drain (Id) @ 25°C	30A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	6.5V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	235nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	13600pF @ 25V
Vgs (Max)	±30V
FET Feature	-
Power Dissipation (Max)	960W (Tc)
Rds On (Max) @ Id, Vgs	360 mOhm @ 15A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-264AA (IXFK)
Package / Case	TO-264-3, TO-264AA
	Report errors?

IXFK30N110P Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

IXFK30N110P Payment Methods



















IXFK30N110P Shipping Methods













If you have any question about IXFK30N110P, please do not hesitate to contact us!

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